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Two-step transition in a magnetoelectric ferrimagnet Cu₂OSeO₃

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We report a detailed single-crystal investigation of a magnetoelectric ferrimagnet Cu_2OSeO_3 using dc magnetization and ac susceptibility along the three principal directions [100], [110], and [111]. We have observed that in small magnetic fields two magnetic transitions occur, one at $T_c = 57$ K and the second one at $T_N = 58$ K. At T_c the nonlinear susceptibility reveals the emergence of the ferromagnetic component and below T_c the magnetization measurements show the splitting between field-cooled and zero-field-cooled regimes. Above 1000 Oe the magnetization saturates and the system is in a single domain state. The temperature dependence of the saturation below T_c can be well described by $\mu(T) = \mu(0)[1 - (T/T_c)^2]^{\beta}$, with $\mu(0) = 0.56\mu_B/Cu$, corresponding to the 3-up-1-down configuration. The dielectric constant measured on a thin single crystal shows a systematic deviation below the transition, indicating an intrinsic magnetoelectric effect.

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I. INTRODUCTION

Although first investigations of magnetoelectrics were performed in 1960s, ¹ a revitalization of the interest in this type of materials came with the discovery of a colossal magnetoelectric effect in manganites *R*MnO₃ (Ref. 2) and *R*Mn₂O₅ (Ref. 3). Since then numerous materials have been investigated with different types of coupling between the electric and magnetic order parameters. ⁴ The prospect of using these materials in new types of memory elements where the magnetic order could be easily manipulated with the applied voltage is stimulating further investigation of new materials.

Recently, it was shown that Cu₂OSeO₃, a ferrimagnet below ≈60 K, shows a magnetoelectric effect below the magnetic transition.⁵ This has been revealed through the change of the dielectric constant across the magnetic transition⁵ and later confirmed by infrared measurements. 6,7 Cu₂OSeO₃ crystallizes in a cubic space group $P2_13$ and a high-resolution structural investigation revealed that it remains metrically cubic down to 10 K (Ref. 5). There are two crystallographically inequivalent copper sites, Cu^I within a trigonal bipyramidal Cu^IO₅ unit and Cu^{II} within a square pyramidal Cu^{II}O₅ unit. Both copper ions are in a 2+ oxidation state, resulting in one unpaired electron per site, giving rise to spin S = 1/2on each magnetic ion. The observed ferrimagnetic structure is a result of a Cu^{I} : $Cu^{II} = 1:3$ ratio, with all the moments pointing along the space diagonal.⁵ From the neutron scattering experiments it has been found that the coupling between the nearest-neighbor (NN) moments is antiferromagnetic for Cu^I-Cu^{II} and ferromagnetic for Cu^{II}-Cu^{II} (Ref. 5), which was later confirmed by the NMR study.8

The exact nature of the magnetoelectric coupling in Cu_2OSeO_3 is still unclear and deeper insight is needed in the basic magnetic properties of the system. It is especially important to elucidate the details of the magnetic transition where the dielectric measurements on powdered sample showed the critical behavior.⁵ In this report we present detailed dc magnetization and ac susceptibility measurements along three principal directions in the cubic system ([100], [110], and [111]). Our results show that in zero field the domain

structure becomes important, giving rise to a complicated M-H dependence as the field is applied. A rather small field of 1000 Oe is enough to drive the system to saturation, where the value of the magnetization of the plateau follows the same temperature dependence found for the internal field by μ SR (Ref. 9). However, in zero field the susceptibility above the transition does not show the critical behavior. Also, our dielectric measurements did not reveal a strong kink at the transition, as observed for the powdered sample. On the other hand, below the transition the dielectric constant deviates from the high-temperature behavior, supporting the conclusion about the magnetoelectric effect in Cu₂OSeO₃.

II. EXPERIMENTAL DETAILS

Single crystals were prepared by the chemical vapor phase method. Details of the preparation can be found in previous reports.^{6,8} The orientation of single crystals was performed using the x-ray Laue camera after which the samples were cut into shapes with dimensions of $1 \times 1 \times 4$ mm³, with the longest side along [100], [110], and [111].

Magnetization measurements were performed on a commercial Quantum Design MPMS5 magnetometer with a temperature range of 2 K–800 K and magnetic fields up to 5 T. The ac susceptibility was measured using a commercial CryoBIND system with a temperature range of 4 K–400 K and a frequency range of 10 mHz–10 kHz. The dielectric response was measured using the home-made setup with the HP 4284A LCR meter in the frequency range 20 Hz–1 MHz, with excitation voltages of 50 mV and 1 V. The sample used has a plan-parallel shape with a cross section of 2.8 mm² and a thickness of 0.4 mm. The contacts were prepared using DuPont 4929N silver paint.

III. RESULTS

In Fig. 1 we present a detailed investigation of the temperature dependence of the magnetization (M) for various applied fields below the transition for all three principal directions. Two sets of measurements are presented for each

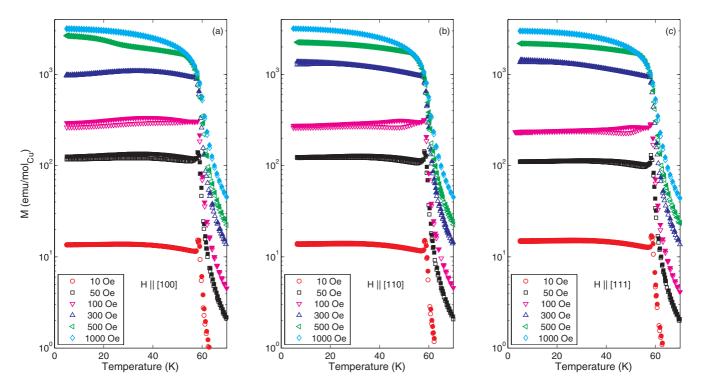


FIG. 1. (Color online) Temperature dependence of the magnetization for (a) [100], (b) [110], and (c) [111] directions. Upper branches (solid symbols) correspond to the FC regime, while the lower branches (open symbols) correspond to the ZFC regime.

field, field-cooled (FC) and zero-field-cooled (ZFC) curves. The procedure for ZFC measurements includes cooling the sample in zero field, applying the field and measuring while warming up. FC measurements were performed while cooling the sample with the field applied.

A noticeable feature is the development of the difference between ZFC and FC curves. For a small field ($H \approx 10$ Oe) no difference is observed. As the field is increased ($H \approx 100$ Oe), the splitting starts below the transition, goes through a maximum around 40 K–50 K and then decreases. For even larger fields ($H \approx 500$ Oe) ZFC and FC curves overlap down to 20 K–30 K and then gradually split below 20 K. Finally, for fields $H \gtrsim 1000$ Oe again no splitting occurs. These observations are in accordance with the results from the powder investigation, where an opening of a small hysteresis loop was reported in the range 300–500 Oe.

Of the three principal directions, [100] shows a somewhat different behavior compared to [110] and [111] (which are qualitatively very similar) regarding the development of the FC-ZFC splitting. For H=10 and 1000 Oe fields all three directions show almost identical behavior. However, already for 50 Oe the measured FC-ZFC difference is larger for the [100] direction. With 100 Oe it persists down to lowest temperatures with H|[100] while for the other two directions it decreases toward zero (more so for H|[111]). For H=300 Oe $M^{[100]}$ reveals a broad maximum around 40 K, where $M^{[110]}$ and $M^{[111]}$ continue to increase down to 5 K. Finally, with H=500 Oe, there is a change in the slope in $M^{[100]}$ around 25 K. All this points to a very complicated mechanism of magnetization processes which is very sensitive to small fields and the orientation of the sample.

To gain insight into this complicated field behavior, we have measured the field dependence of the magnetization. Each curve in Fig. 2 was recorded after the sample was cooled down from above the transition with the applied magnetic field of H = 2000 Oe (FC regime).

All the curves exhibit a quasilinear regime below 600–1000 Oe (depending on temperature) above which the saturation plateau is reached. Additionally, as the temperature is lowered below 50 K a metamagnetic transition occurs around 250 Oe for the [110] and [111] directions. The [100] direction is again somewhat different qualitatively and quantitatively, with a characteristic field above 400 Oe.

The saturation values at all temperatures are identical for all three directions. This means that the sample becomes a single domain for relatively small applied fields (≈ 1000 Oe at 5 K), which suggests that Cu_2OSeO_3 exhibits a Heisenberg anisotropy to a very good approximation.

For that reason it is interesting to look more closely into the temperature dependence of the average magnetic moment per Cu ion $\mu(T)$ when the sample is saturated. In Fig. 3 we plot the results for $H \parallel [110]$. The solid line represents the fit to a power law,

$$\mu(T) = \mu(0) \left[1 - \left(\frac{T}{T_c} \right)^{\alpha} \right]^{\beta}, \tag{1}$$

which has also been used to describe the internal field behavior in the μ SR study. If the parameter α is varied in the fitting procedure, it yields the value $\alpha=1.95$, very close to 2.00 obtained in the μ SR study. $\alpha=2$ is supported by the general observation that the variation of the order parameter close to $\alpha=1.95$ to the parameter close to $\alpha=1.95$ to the depends only on the dimensionality and the value of

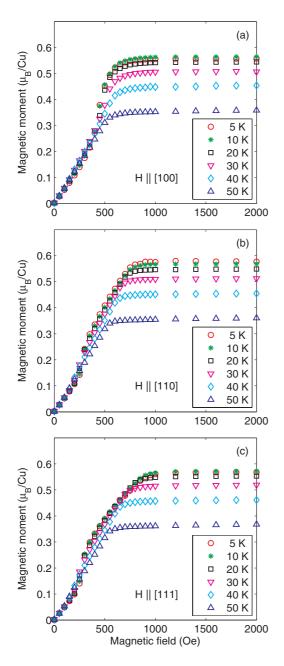


FIG. 2. (Color online) Average magnetic moment on the cooper ion vs magnetic field for (a) [100], (b) [110], and (c) [111] directions.

the spin quantum number.¹⁰ Thus, we have fixed $\alpha=2$ and allowed other parameters to be determined by the fit. The fitting has been performed on the total of six curves (three directions, FC and ZFC conditions). Averaging all the results gives $\mu(0)=0.559(7)\mu_B$, $T_c^{\rm critical}=59.85(5)$ K, and $\beta=0.393(4)$ for the saturation value, critical temperature, and critical exponent, respectively.

The value of the critical exponent β agrees with the value deduced by μ SR (Ref. 9). It is very close to the theoretical value for a 3D Heisenberg system ($\beta^{\text{Heis},3D}=0.365$) and it is in excellent agreement with the values obtained for various shapes of the polycrystalline Ni samples.¹¹

 $T_c^{\text{critical}} = 59.85 \text{ K}$ is somewhat higher than deduced from the μSR study (57 K). The crucial difference is that in our

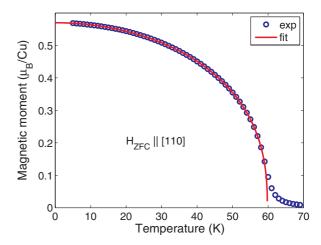


FIG. 3. (Color online) Temperature dependence of the saturated magnetization in 1000 Oe for the [110] direction. The line is a fit to Eq. (1).

case the sample experienced an external magnetic field of H=1000 Oe, while the μSR study was performed in a zero-field condition. In a recent study of the field dependence of the transition¹² it has been revealed that there is a rather strong positive coefficient where T_c increases by 10 K in H=7 T. However, their conclusion was that the transition remains immobile up to 1 T. On the other hand, their method involved the derivative of the magnetization which is not sensitive enough to reliably determine such a small change.

The saturation value at low temperatures $\mu(0) = 0.559(7)\mu_B$ corresponds to the 3-up-1-down configuration where 3-up is associated with Cu^{II} ions and 1-down with a Cu^{II} ion. The remarkable fact is that Eq. (1) describes the data in the whole temperature range, with the critical behavior for $T \to 0$ and $T \to T_c$, which is rarely found even in much simpler systems.

Now it is interesting to look more closely at how the system transforms from the paramagnetic to the ferrimagnetic state. In Fig. 4 we show the expanded view around 60 K, covering the transition to the ordered state. In the top panel we present the comparison between the ac and dc results in small fields, measured with 0.1 and 10 Oe, respectively. The ac susceptibility χ_1^{ac} has been normalized so that it matches the dc susceptibility χ^{dc} in the paramagnetic regime above 70 K but one can notice that they overlap even lower, down to \approx 62 K. No frequency dependence of the ac susceptibility was observed, confirming the previous finding. The nonlinear response, measured with a third harmonic of the ac susceptibility χ_3^{ac} , is shown in the bottom panel.

Since the ac susceptibility is measured in the sweep mode, it is easier to notice the subtle features often missed in stepwise curves, usually associated with the extraction method. One can notice that the divergentlike behavior of the susceptibility, expected from a ferrimagnet, exists down to 59 K but then it turns into an S-shape curve and the criticality is avoided. This is even more evident when the derivative of the susceptibility is calculated (see the middle panel of Fig. 4). The slope of the curve gets more and more negative until it reaches the maximum negative value just below 59 K, marking the presence of an inflection point. In comparison,

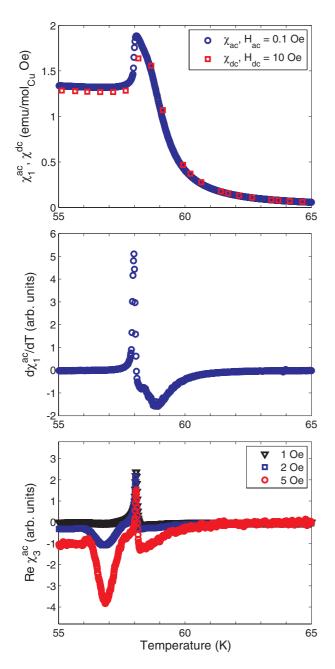


FIG. 4. (Color online) Temperature dependence of the susceptibility around the transition for the [111] direction. (Top) Linear susceptibility (ac and dc). (Middle) A derivative of the linear ac susceptibility. (Bottom) The third harmonic of the ac susceptibility.

the dc susceptibility data show the ambiguity even for the determination of the transition temperature due to a relatively large step between points (0.5 K in our case; cf. Ref. 6 with a 1 K step). At $T_N = 58$ K a sharp drop is observed, marking the transition to the ordered state. It is instructive to mention that the same behavior of the ac susceptibility is observed for all the investigated directions.

In the bottom panel of Fig. 4 we present the results of the nonlinear susceptibility measurements. This technique is recognized as a powerful tool in the description of magnetic transitions, first from the theoretical point of view¹³ and then with an implementation for ferromagnets, ^{14,15} antiferromagnets, ¹⁶

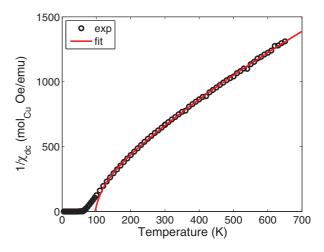


FIG. 5. (Color online) Temperature dependence of the inverse dc susceptibility. The line is a fit to Eq. (2).

spin glasses, and superparamagnets.¹⁷ One can categorize the system by its dependence on the field amplitude and the observation of divergences on both sides of the transition.

The shape of the nonlinear response around $T_N = 58$ K strongly suggests an antiferromagnetic nature of the ordered state ^{13,16}: It is diverging below T_N but nondiverging above T_N . A surprising discovery is the presence of a second peak in the nonlinear part of the susceptibility $\chi_3^{\rm ac}$, centered at $T_c = 57$ K. This is accompanied by a broad minimum in $\chi_1^{\rm ac}$, after which a slow increase of $\chi_1^{\rm ac}$ is observed as the temperature is lowered. The peak magnitude increases with an increase of the amplitude of the driving field, suggesting the emergence of a ferromagnetic component in the system, in line with the observation of the appearance of the internal field from the μ SR study.

Above the transition the system is in a paramagnetic regime. It has been suggested⁸ that it can be described within a mean-field approach, taking into account one ferromagnetic (Cu^{II}-Cu^{II}) and one antiferromagnetic (Cu^I-Cu^{II}) interaction. The susceptibility for $T > T_C$ is given by the expression

$$\chi = \frac{g^2 S(S+1)\mu_B^2}{3k_B (T-T_C)} \frac{T - \frac{1}{4}(|J_{\rm FM}| + 3J_{\rm AFM})}{T + T_C - |J_{\rm FM}|} + \chi_0, \quad (2)$$

where $J_{\rm FM}\approx-52$ K, $J_{\rm AFM}\approx75$ K, $\chi_0=1.3\times10^{-4}$ emu/mol Oe, and the mean-field critical temperature is given by $T_C=(|J_{\rm FM}|+\sqrt{J_{\rm FM}^2+3J_{\rm AFM}^2})/2\approx90$ K. As presented in Fig. 5, this model describes well the experimental data above 130 K.

The initial report by Bos and co-workers⁵ suggested that the magnetoelectric effect emerges coincidently with the magnetic transition occurring at 60 K. Given the fact that we have revealed the existence of two magnetic transitions, it is crucial to try to connect one of them to the dielectric properties of the system. To this end, we have performed a similar investigation of the dielectric properties. At all temperatures we observe a purely real dielectric response with no significant dependence on frequency in our measurement range. In Fig. 6 we present the results of the measurement performed with 10 kHz and 1 V excitation. Very similar results have been obtained at lower

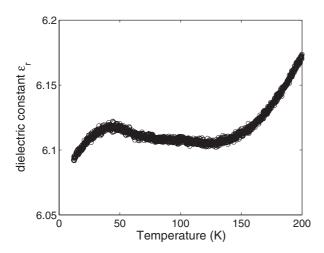


FIG. 6. The temperature dependence of the dielectric constant of Cu₂OSeO₃ measured at 10 kHz and 1 V.

frequencies and a lower excitation value of 50 mV, except for an increase in the noise level.

Compared with the results on the powder,⁵ our data show somewhat different behavior. ϵ_r levels off below 130 K and exhibits a maximum around 45 K. We are unable to identify the presence of a kink around the magnetic transition from which the critical behavior of ϵ_r has been extracted.⁵ However, below 45 K ϵ_r starts to decrease, very similar to the previous report.⁵ Also, the values of the dielectric constant are different; we obtain $\epsilon_r \approx 6.1$ while for the powdered sample it was obtained that $\epsilon_r \approx 14.3$.

The discrepancies between our single-crystal investigation and the results of Bos and co-workers on the powdered sample can have several explanations. First, the measurements on the powdered sample are prone to a parasitic intergrain capacitance, the so-called Maxwell-Wagner effect. Second, the retentive properties of the silver paint applied to the pellet and to the smooth surface of the single crystal are very different. One has to bear in mind that, at least in our case, the total change in capacitance below 150 K corresponds to only 1 fF. Thus, even a minute change in the contact properties or even in cables could affect the measurement. Although our results were reproducible in several cooling cycles, we cannot exclude the possibility of a reversible change in contacts and its extrinsic contribution. On the other hand, the observation of a maximum around 45 K and a subsequent drop of ϵ_r at lower temperatures is seen in both the powdered and single-crystal form, indicating an intrinsic effect.

IV. DISCUSSION

Previous reports suggested a single magnetic transition from a paramagnetic to a ferrimagnetic state occurring around 60 K, which was accompanied by a change in the dielectric constant, revealing a magnetoelectric effect. However, the ac susceptibility data shown in Fig. 4 show that the transition to the ordered state of Cu₂OSeO₃ is not a simple one and requires a deeper insight.

We have found the signatures of two transitions, one at $T_c = 57$ K and one at $T_N = 58$ K. At T_c the nonlinear susceptibility revealed that a ferromagnetic component emerges in the

TABLE I. Cu-O-Cu bridges in Cu₂OSeO₃. The bridges between the horizontal lines form a single magnetic interaction.

Туре	Angle (deg)	Distance (Å)
Cu^{I} -O(2)- Cu^{II}	117.9	1.909/2.038
Cu^{I} - $O(1)$ - Cu^{II}	107.8	1.925/1.854
Cu^{I} -O(3)- Cu^{II}	94.15	2.082/2.089
Cu^{\parallel} -O(1)- Cu^{\parallel}	111.05	1.854
Cu^{II} -O(2)- Cu^{II}	99.92	2.038
Cu^{\parallel} -O(4)- Cu^{\parallel}	94.77	1.896

system which is in agreement with previous neutron⁵ and μ SR⁹ studies. We can consider that for $T < T_c$ the system is in a ferrimagnetic 3-up-1-down state with moments pointing along the space diagonal.⁵ The cubic symmetry is maintained down to the lowest temperatures, ^{5,8} which means that there are four equivalent space diagonals and each diagonal can have two directions of the composite moment. The minimization of the free energy will result in the creation of domains with eight preferential directions. The rise of the linear component of the susceptibility below T_c for small fields can then be understood as a consequence of the dynamics of domain walls.

Let us now discuss the possible origin of the transition at T_N . It is characterized by a sharp drop in the linear component of the susceptibility, observed for all the investigated directions ([100], [110], and [111]). The nonlinear component of the susceptibility displays a divergentlike branch below T_N and a nondivergent branch above T_N , which are characteristic features for a transition to the antiferromagnetic state. ^{13,16} However, for a simple, canonical easy-axis antiferromagnet¹⁸ one would expect for linear components $\chi_1^{[100]}$ and $\chi_1^{[110]}$, although not perpendicular to [111], to show a noticeable difference compared to $\chi_1^{[111]}$.

The mean-field approach, suggested by Belesi and coworkers, takes into account only two types of interactions, Cu^I-Cu^{II} (AFM) and Cu^{II}-Cu^{II} (FM). However, a careful inspection of the crystal structure reveals that there are several Cu-O-Cu bridges that can influence the magnetic behavior of the system. In Table I we list the associated angles and distances, grouped to form NN interactions. According to the Goodenough-Kanamori-Anderson rule, the exchange interaction *J* changes from AFM to FM as the Cu-O-Cu angle approaches 90°. The exact angle where *J* changes sign lies in the range 95°–99° and is also dependent on the influence of the neighboring orbitals. ¹⁹

The presumed equivalence of all the AFM interactions between the central Cu^I moment and six NN Cu^{II} moments is not correct. The single bridge over the O(2) ion on one side can be estimated to be AFM with a moderate strength. However, on the other side there are two bridges, over O(1) and O(3) ions. The coupling over O(1) is also AFM but because of a smaller angle it is weaker in comparison with the O(2) bridge. Additionally, the angle over O(3) indicates the FM coupling, further reducing the total exchange constant (Fig. 7).

Following the same arguments, the presumed single-FM interaction between the NN Cu^{II} moments needs to be revisited. Again there are three bridges forming two exchange interactions. For the bridge over O(1) the angle is $\sim 111^{\circ}$, indicating an AFM coupling. Since the Cu^{II} moments form

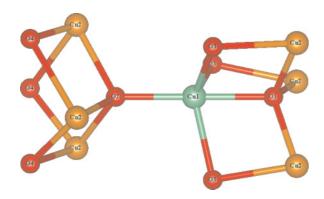


FIG. 7. (Color online) Local environment around Cu^I and Cu^{II} ions in Cu_2OSeO_3 .

a triangle, there is induced frustration. A single interaction is mediated via O(2) and O(4) bridges and its sign cannot be estimated easily. Considering the angles over O(2) and O(4), the couplings should be AFM and FM, respectively, but the exact calculation is needed to determine which type is dominant.

Such a configuration of NN interactions can, in principle, be approximated with a mean-field theory so that on average one FM and one AFM interaction describe well the high-temperature behavior. However, close to the transition one would expect that the details of the couplings start to play an important role. This can explain the overestimation of the critical temperature in the mean-field model.⁸

Below T_c , in the ferrimagnetic state, the magnetization grows linearly when the dc magnetic field is applied. Our results show that all principal directions have very similar M-H slope. We attribute this to the formation of domains along four equivalent space diagonals of the cube. Since each diagonal can have two directions of the composite moment in a ferrimagnet, we have eight preferred domain orientations in total for H = 0. The application of a small magnetic field causes domain walls to move, increasing the volume of domains preferentially oriented in the direction of the field. As the temperature is lowered, the pinning of domain walls becomes important, giving rise to the observed FC-ZFC splitting. Also, depending on the orientation of the applied field, there will be one + three ([111] + [11 $\bar{1}$], [1 $\bar{1}$ 1], [1 $\bar{1}$ 1]), two ([111], [11 $\bar{1}$]), or four ([111], [11 $\overline{1}$], [1 $\overline{1}$ 1], [1 $\overline{1}$ 1]) preferred domains for $H \parallel$ [111], [110], and [100], respectively. This means that there will be a value of the magnetic field H^{meta} where the sample will consist of only preferred domains and for $H > H^{\text{meta}}$ the domains will start to collectively rotate toward the direction of the magnetic field. We suggest that this process is responsible for the observed metamagnetic transition in the range 200–500 Oe, depending on the orientation.

At a sufficiently high field a crossover to a plateau occurs, where the crossover field and the magnetization of the plateau increase as the temperature is decreased. We have found that the magnetization of the plateau is well described by a power law [see Eq. (1)], similar to the zero-field μ SR study. This is easily understood if we take into account that the internal fields sensed by muons are dominated by domains, irrespective of their orientation. Polarizing the sample and measuring its total magnetization should then give the same

temperature dependence. However, a surprising shift of the critical temperature from 57 K in zero-field conditions⁹ to 60 K at H = 1000 Oe is observed. We can speculate that in zero field the ferromagnetic fluctuations are suppressed due to the frustration between the Cu^{II} moments, producing the inflection point at 59 K and avoiding the criticality. The application of a small field is enough to disturb the delicate balance within the interactions in the system and the critical temperature rises up.

In closing, we would like to discuss how our results relate to the observed magnetoelectric effect in Cu₂OSeO₃. The frequency-independent dielectric response suggests an absence of dielectric relaxation processes in the Hz-MHz region, both above and below the two magnetic transitions. We were not able to observe a substantial influence of the magnetic transitions on the value of the dielectric constant. In the initial report Bos and co-workers claimed⁵ that after subtraction of the lattice contribution ϵ_r exhibited a critical behavior around T_N . Together with the evidence that in zero magnetic field the magnetic subsystem shows avoided criticality, we find it questionable whether any kind of criticality exists in the dielectric subsystem. However, the observed maximum around 45 K and the decrease of the dielectric constant below it, which have been also observed on the powdered sample, do suggest the existence of a weak magnetoelectric effect. It is interesting to note that a sizable magnetocapacitance of the powder occurs only below 1000 Oe (Ref. 5). We have demonstrated that this field range is characterized by the presence of domains and domain walls. Thus, we propose that the magnetoelectric effect in Cu₂OSeO₃ arises as a consequence of the rotation of magnetic moments within domain walls. As they spiral from one orientation to another, the (local) spatial symmetry is broken, which allows the emergence of the polarization in a similar fashion, as has been demonstrated in TbMnO₃ (Ref. 2). Recently, it has been shown that such a scenario is realized in iron-garnet thin films.²⁰ This way a rather small change of the dielectric constant can be naturally explained since domain walls occupy only a small fraction of the sample's volume. Further studies are needed to clarify the details of the magnetoelectric coupling.

V. CONCLUSIONS

We have presented a detailed single-crystal magnetization and susceptibility study of Cu_2OSeO_3 . Our results suggest that the transition from the paramagnetic to the ordered state is more complicated than previously reported. The mean-field approach, with one FM and one AFM interaction, works well at higher temperatures. However, close to the transition it is important to take into account more realistic magnetic couplings between the copper ions.

Below the transition the magnetic dynamics is dominated by the presence of domains and domain walls. A rather small field of 1000 Oe is enough to drive the system in a single-domain state, where the magnetization follows the critical behavior and a critical exponent $\beta \approx 0.39$ can be extracted, as published before.⁹

The dielectric measurements showed that below the magnetic transition the dielectric constant deviates from the high-temperature behavior, suggesting a weak magnetoelectric effect related to the presence of domain walls.

Note added in proof. Recent investigations (Refs. 21 and 22) revealed that the ground state in this material can be assigned to be helimagnetic, with a metamagnetic transition observed in our M-H curves to be between the helical and the conical states. For even larger fields the system is polarized in the ferrimagnetic state. There are some discrepancies in the characteristic values of the magnetic field which are probably related to different demagnetization factors.

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